



## SY88933AL

### 3.3V, 1.25Gbps PECL High-Sensitivity Limiting Post Amplifier w/TTL Signal Detect

#### General Description

The SY88933AL high-sensitivity limiting post amplifier is designed for use in fiber-optic receivers. The device connects to typical transimpedance amplifiers (TIAs). The linear signal output from TIAs can contain significant amounts of noise and may vary in amplitude over time. The SY88933AL quantizes these signals and outputs PECL level waveforms.

The SY88933AL operates from a single +3.3V power supply, over temperatures ranging from  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ . With its wide bandwidth and high gain, signal with data rates up to 1.25Gbps and as small as  $5\text{mV}_{\text{PP}}$  can be amplified to drive devices with PECL inputs.

The SY88933AL generates a high gain signal-detect (SD) open-collector TTL output. The SD function has a high gain input stage for increased sensitivity. A programmable signal-detect level set pin ( $\text{SD}_{\text{LVL}}$ ) sets the sensitivity of the input amplitude detection. SD asserts high if the input amplitude rises above the threshold set by  $\text{SD}_{\text{LVL}}$  and de-asserts low otherwise. The enable input (EN) de-asserts the true output signal without removing the input signal. The SD output can be fed back to the EN input to maintain output stability under a loss-of-signal condition. Typically, 3.4dB SD hysteresis is provided to prevent chattering.

All support documentation can be found on Micrel's web site at: [www.micrel.com](http://www.micrel.com).

#### Features

- Single 3.3V power supply
- DC-to-1.25Gbps operation
- Low-noise PECL data outputs
- High gain SD
- Chatter-free open-collector TTL signal detect (SD) output with internal  $4.75\text{k}\Omega$  pull-up resistor
- TTL EN input
- Programmable SD level set ( $\text{SD}_{\text{LVL}}$ )
- Available in a tiny 10-pin MSOP package
- Pin-compatible with SY88933V

#### Applications

- GPON/BPON/EPON/GEPON
- Gigabit Ethernet
- 531Mbps and 1062Mbps Fibre Channel
- OC-3 and OC-12 SONET/SDH
- High-gain line driver and line receiver
- Low-gain TIA interface

#### Markets

- FTTX
- Optical transceiver
- Datacom/telecom

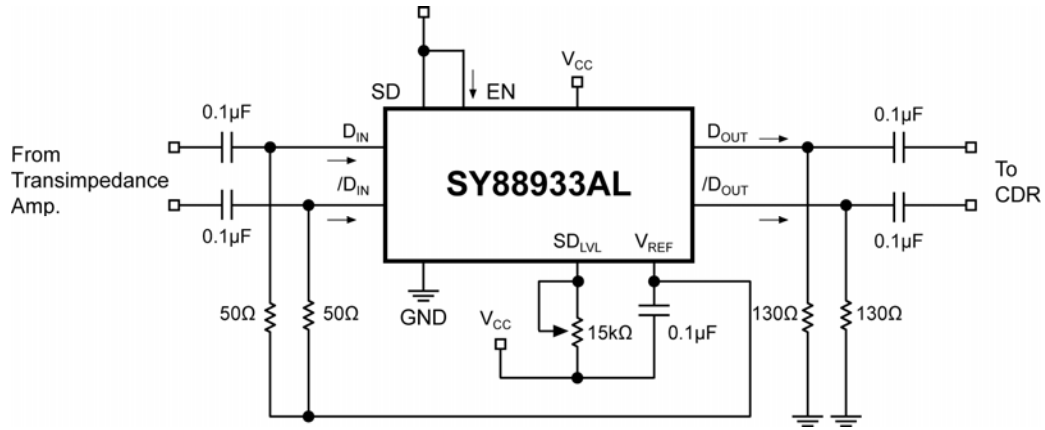
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### Typical Application Circuit



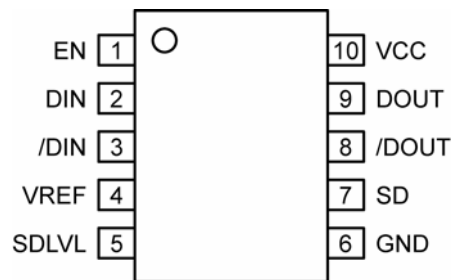
## Ordering Information

Part Number	Package Type	Operating Range	Package Marking	Lead Finish
SY88933ALKG	K10-1	Industrial	933A with Pb-Free bar line indicator	NiPdAu Pb-Free
SY88933ALKGTR <sup>(1)</sup>	K10-1	Industrial	933A with Pb-Free bar line indicator	NiPdAu Pb-Free
SY88933ALKI	K10-1	Industrial	933A	SnPb
SY88933ALKITR <sup>(1)</sup>	K10-1	Industrial	933A	SnPb

**Note:**

1. Tape and Reel.

## Pin Configuration



10-Pin MSOP (K10-1)

## Pin Description

Pin Number	Pin Name	Type	Pin Function
1	EN	TTL Input: Default is HIGH.	Enable: This input enables the outputs when it is HIGH. Note that this input is internally connected to a 25k $\Omega$ pull-up resistor and will default to a logic HIGH state if left open.
2	DIN	Data Input	True data input.
3	/DIN	Data Input	Complementary data input.
4	VREF		Reference voltage: Placing a capacitor here to V <sub>CC</sub> helps stabilize SD <sub>LVL</sub> .
5	SDLVL	Input	Signal-Detect Level Set: a resistor from this pin to V <sub>CC</sub> sets the threshold for the data input amplitude at which SD will be asserted.
6	GND	Ground	Device ground.
7	SD	Open-collector TTL output w/internal 4.75k $\Omega$ pull-up resistor	Signal-Detect: asserts high when the data input amplitude rises above the threshold set by SD <sub>LVL</sub> .
8	/DOUT	PECL Output	Complementary data output.
9	DOUT	PECL Output	True data output.
10	VCC	Power Supply	Positive power supply.

**Absolute Maximum Ratings<sup>(1)</sup>**

Supply Voltage ( $V_{CC}$ )	0V to +7.0V
Input Voltage (DIN, /DIN)	0 to $V_{CC}$
Output Current ( $I_{OUT}$ )	
Continuous	50mA
Surge	100mA
EN Voltage	0 to $V_{CC}$
$V_{REF}$ Current	-800 $\mu$ A to +500 $\mu$ A
$SD_{LVL}$ Voltage	$V_{REF}$ to $V_{CC}$
Lead Temperature (soldering, 20sec.)	260°C
Storage Temperature ( $T_s$ )	-65°C to +150°C

**Operating Ratings<sup>(2)</sup>**

Supply Voltage ( $V_{CC}$ )	+3.0V to +3.6V
Ambient Temperature ( $T_A$ )	-40°C to +85°C
Junction Temperature ( $T_J$ )	-40°C to +120°C
Junction Thermal Resistance	
MSOP ( $\theta_{JA}$ ) Still-air	113°C/W

**DC Electrical Characteristics**

$V_{CC} = +3.0V$  to +3.6V;  $R_{LOAD} = 50\Omega$  to  $V_{CC}-2V$ ;  $T_A = -40^\circ C$  to +85°C; typical values at  $V_{CC} = +3.3V$ ,  $T_A = +25^\circ C$ .

Symbol	Parameter	Condition	Min	Typ	Max	Units
$I_{CC}$	Power Supply Current	No output load		26	39	mA
$SD_{LVL}$	$SD_{LVL}$ Voltage		$V_{REF}$		$V_{CC}$	V
$V_{OH}$	PECL Output HIGH Voltage		$V_{CC}-1.085$	$V_{CC}-0.955$	$V_{CC}-0.880$	V
$V_{OL}$	PECL Output LOW Voltage		$V_{CC}-1.850$	$V_{CC}-1.705$	$V_{CC}-1.555$	V
$V_{IHCMR}$	Common Mode Range		GND+2.0		$V_{CC}$	V
$V_{REF}$	Reference Voltage		$V_{CC}-1.48$	$V_{CC}-1.32$	$V_{CC}-1.16$	V

**TTL DC Electrical Characteristics**

$V_{CC} = 3.0V$  to 3.6V;  $R_{LOAD} = 50\Omega$  to  $V_{CC}-2V$ ;  $T_A = -40^\circ C$  to +85°C.

Symbol	Parameter	Condition	Min	Typ	Max	Units
$V_{IH}$	EN Input HIGH Voltage		2.0			V
$V_{IL}$	EN Input LOW Voltage				0.8	V
$I_{IH}$	EN Input HIGH Current	$V_{IN} = 2.7V$ $V_{IN} = V_{CC}$			20 100	$\mu$ A $\mu$ A
$I_{IL}$	EN Input LOW Current	$V_{IN} = 0.5V$	-0.3			mA
$V_{OH}$	SD Output HIGH Level	$V_{CC} \geq 3.3V$ , $I_{OH-MAX} < 160\mu A$ $V_{CC} < 3.3V$ , $I_{OH-MAX} < 160\mu A$	2.4 2.0			V V
$V_{OL}$	SD Output LOW Level	$I_{OL} = +2mA$			0.5	V

**Notes:**

- Permanent device damage may occur if absolute maximum ratings are exceeded. This is a stress rating only and functional operation is not implied at conditions other than those detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
- The data sheet limits are not guaranteed if the device is operated beyond the operating ratings.

## AC Electrical Characteristics

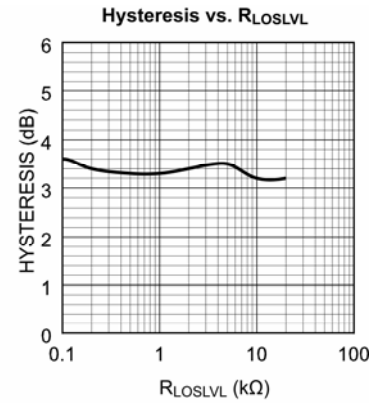
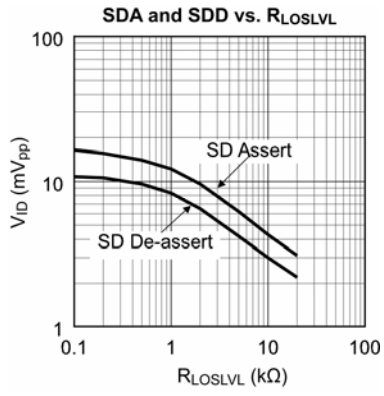
$V_{CC} = 3.0V$  to  $3.6V$ ;  $R_{LOAD} = 50\ \Omega$  to  $V_{CC}-2V$ ;  $T_A = -40^\circ C$  to  $+85^\circ C$ ; typical values at  $V_{CC} = +3.3V$ ,  $T_A = +25^\circ C$ .

Symbol	Parameter	Condition	Min	Typ	Max	Units
PSRR	Power Supply Rejection Ratio			35		dB
$t_r, t_f$	Output Rise/Fall Time (20% to 80%)	Note 3			260	ps
$t_{JITTER}$	Deterministic Random	Note 4 Note 5		15 5		ps <sub>pp</sub> ps <sub>RMS</sub>
$V_{ID}$	Differential Input Voltage Swing	Figure 1	5		1800	mV <sub>pp</sub>
$V_{OD}$	Differential Output Voltage Swing	$V_{ID} \geq 18mV_{pp}$ , Figure 1		1500		mV <sub>pp</sub>
$T_{OFF}$	SD Release Time			2	10	$\mu s$
$T_{ON}$	SD Assert Time			2	10	$\mu s$
$SD_{AL}$	Low SD Assert Level	$R_{SDLVL} = 15k\Omega$ , Note 6		3.4	6.5	mV <sub>pp</sub>
$SD_{DL}$	Low SD De-assert Level	$R_{SDLVL} = 15k\Omega$ , Note 6	1.0	2.3		mV <sub>pp</sub>
$HYS_L$	Low SD Hysteresis	$R_{SDLVL} = 15k\Omega$ , Note 7	1	3.4	4.5	dB
$SD_{AM}$	Medium SD Assert Level	$R_{SDLVL} = 5k\Omega$ , Note 6		6.2	8	mV <sub>pp</sub>
$SD_{DM}$	Medium SD De-assert Level	$R_{SDLVL} = 5k\Omega$ , Note 6	3	4.2		mV <sub>pp</sub>
$HYS_M$	Medium SD Hysteresis	$R_{SDLVL} = 5k\Omega$ , Note 7	2	3.4	4.5	dB
$SD_{AH}$	High SD Assert Level	$R_{SDLVL} = 100\Omega$ , Note 6		16.4	20	mV <sub>pp</sub>
$SD_{DH}$	High SD De-assert Level	$R_{SDLVL} = 100\Omega$ , Note 6	8	10.8		mV <sub>pp</sub>
$HYS_H$	High SD Hysteresis	$R_{SDLVL} = 100\Omega$ , Note 7	2	3.4	4.5	dB
$B_{-3dB}$	3dB Bandwidth			1		GHz
$A_{V(Diff)}$	Differential Voltage Gain			42		dB
$S_{21}$	Single-Ended Small-Signal Gain		30	36		dB

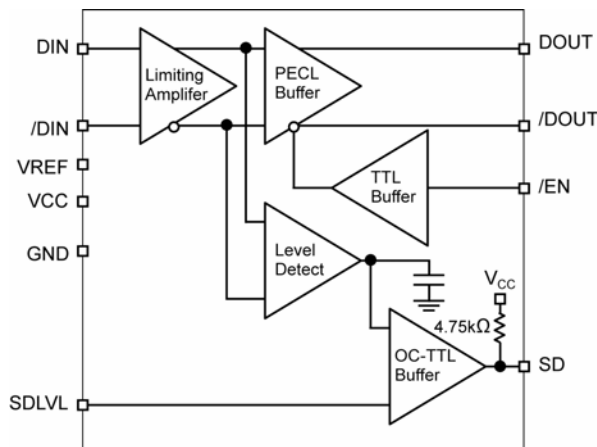
### Notes:

- Amplifier in limiting mode. Input is a 200MHz square wave.
- Deterministic jitter measured using 1.25Gbps K28.5 pattern,  $V_{ID} = 10mV_{pp}$ .
- Random jitter measured using 1.25Gbps K28.7 pattern,  $V_{ID} = 10mV_{pp}$ .
- See "Typical Operating Characteristics" for a graph showing how to choose a particular  $R_{SDLVL}$  for a particular SD assert and its associated de-assert amplitude.
- This specification defines electrical hysteresis as  $20\log$  (SD Assert/SD De-assert). The ratio between optical hysteresis and electrical hysteresis is found to vary between 1.5 and 2 depending upon the level of received optical power and ROSA characteristics. Based on that ratio, the optical hysteresis corresponding to the electrical hysteresis range 1dB-4.5 dB, shown in the AC characteristics table, will be 0.5dB-3dB optical hysteresis

## Typical Characteristics



## Functional Block Diagram



## Detailed Description

The SY88933AL low-power limiting post amplifier operates from a single +3.3V power supply, over temperatures from  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ . Signals with data rates up to 1.25Gbps, and as small as  $5\text{mV}_{\text{pp}}$ , can be amplified. Figure 1 shows the allowed input voltage swing. The SY88933AL generates an SD output.  $\text{SD}_{\text{LVL}}$  sets the sensitivity of the input amplifier section.

### Input Amplifier/Buffer

Figure 2 shows a simplified schematic of the SY88933AL's input stage. The high-sensitivity of the input amplifier allows signals as small as  $5\text{mV}_{\text{pp}}$  to be detected and amplified. The input amplifier also allows input signals as large as  $1800\text{mV}_{\text{pp}}$ . Input signals are linearly amplified with a typical 42dB differential voltage gain. Since it is a limiting amplifier, the SY88933AL outputs typically  $1500\text{mV}_{\text{pp}}$  voltage-limited waveforms for input signals that are greater than  $12\text{mV}_{\text{pp}}$ . Applications requiring the SY88933AL to operate with high-gain should have the upstream TIA placed as close as possible to the SY88933AL's input pins to ensure the best performance of the device.

### Output Buffer

The SY88933AL's PECL output buffer is designed to drive  $50\Omega$  lines. The output buffer requires appropriate termination for proper operation. An external  $50\Omega$  resistor to  $V_{\text{CC}}-2\text{V}$  for each output pin provides this. Figure 3 shows a simplified schematic of the output stage.

### Signal-Detect

The SY88933AL generates a chatter-free SD open-collector TTL output with an internal  $4.75\text{k}\Omega$  pull-up resistor as shown in Figure 4. SD is used to determine that the input amplitude is large enough to be considered a valid input. SD asserts high if the input amplitude rises above the threshold set by  $\text{SD}_{\text{LVL}}$  and de-asserts low otherwise. SD can be fed back to the enable (EN) input to maintain output stability under a loss of signal condition. EN de-asserts the true output signal without removing the input signals. Typically, 3.4dB SD hysteresis is provided to prevent chattering.

### Signal-Detect Level Set

A programmable SD level set pin ( $\text{SD}_{\text{LVL}}$ ) sets the threshold of the input amplitude detection. Connecting an external resistor between  $V_{\text{CC}}$  and  $\text{SD}_{\text{LVL}}$  sets the voltage at  $\text{SD}_{\text{LVL}}$ . This voltage ranges from  $V_{\text{CC}}$  to  $V_{\text{REF}}$ . The external resistor creates a voltage divider between  $V_{\text{CC}}$  and  $V_{\text{REF}}$ , as shown in Figure 5.

### Hysteresis

The SY88933AL provides typically 3.4dB SD electrical hysteresis. By definition, a power ratio measured in dB is  $10\log(\text{power ratio})$ . Power is calculated as  $V_{\text{IN}}^2/R$  for an electrical signal. Hence, the same ratio can be stated as  $20\log(\text{voltage ratio})$ . While in linear mode, the electrical voltage input changes linearly with the optical power and hence, the ratios change linearly. Therefore, the optical hysteresis in dB is half the electrical hysteresis in dB given in the data sheet. The SY88933AL is an electrical device, and this data sheet refers to hysteresis in electrical terms. With 3.4dB SD hysteresis, a voltage factor of 1.5 is required to assert or de-assert SD.

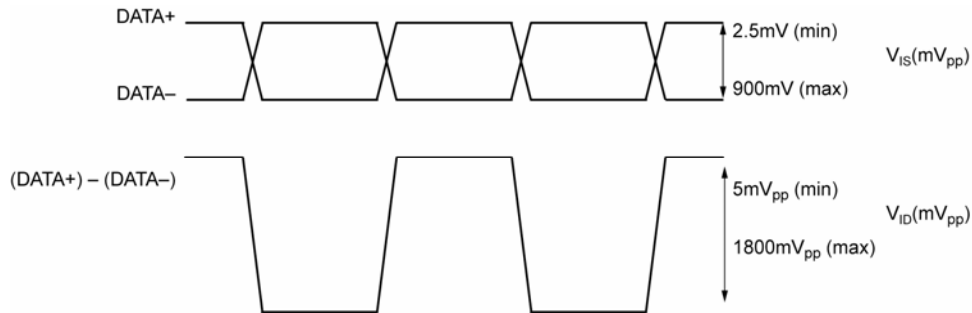


Figure 1.  $V_{IS}$  and  $V_{ID}$  Definitions

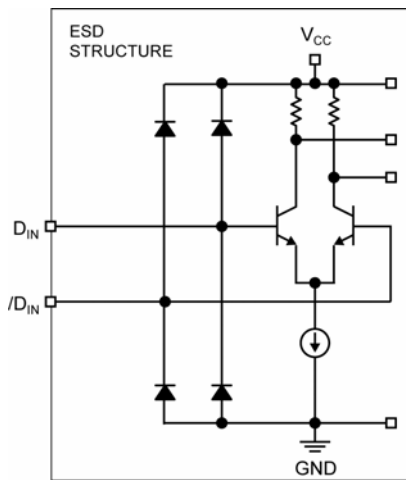


Figure 2. Input Structure

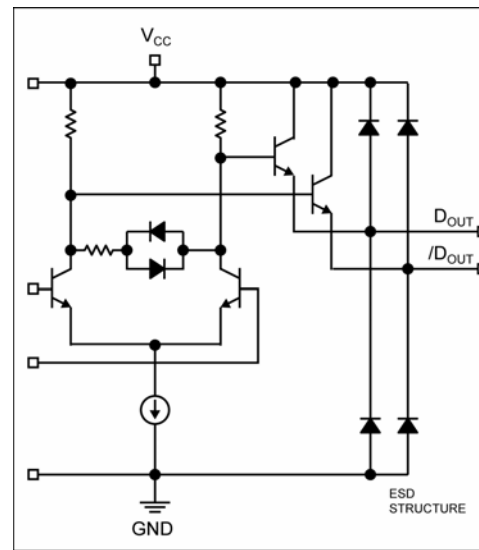


Figure 3. Output Structure

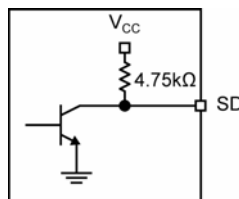


Figure 4. SD Output Structure

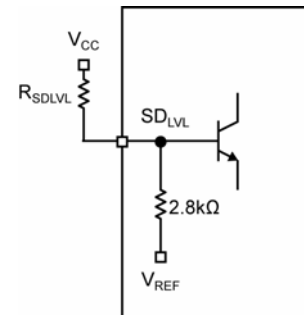


Figure 5.  $SD_{LVL}$  Setting Circuit

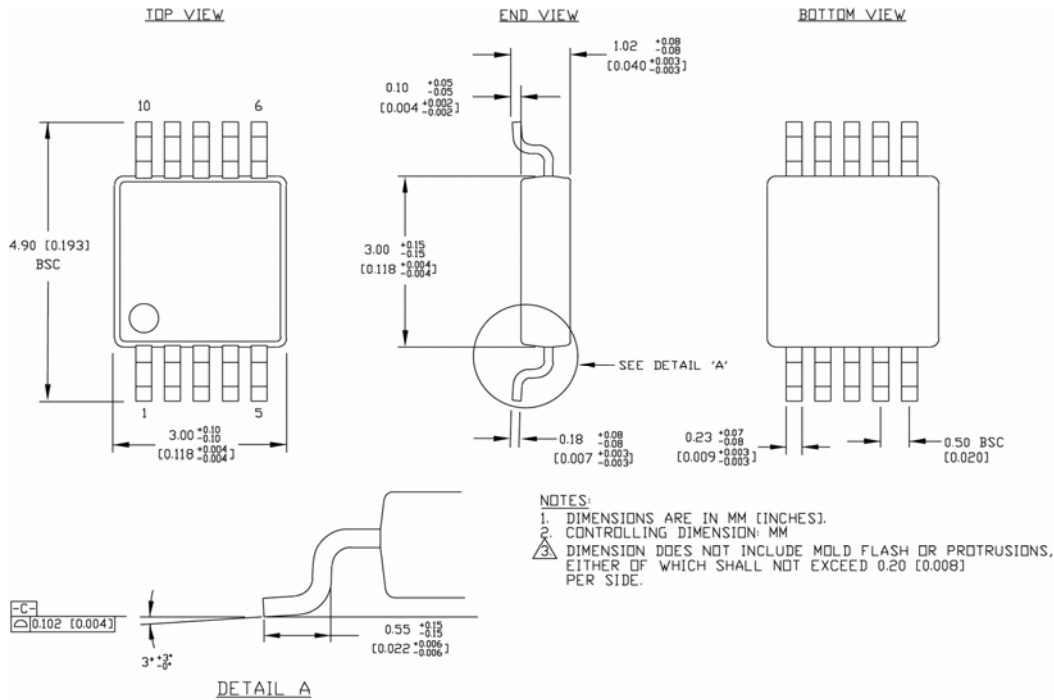
Note: Recommended value for  $R_{SDLVL}$  is 15kΩ or less.

Related Product and Support Documentation

Part Number	Function	Data Sheet Link
Application Notes	Notes on Sensitivity and Hysteresis in Micrel Post Amplifiers	<a href="http://www.micrel.com/product-info/app_hints+notes.shtml">http://www.micrel.com/product-info/app_hints+notes.shtml</a>



**Package Information**



Rev. 00

**10-Pin MSOP (K10-1)**

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